

/ Descriptions

DFN0603

ESD

DFN0603 Plastic Package 1-Line,Bi-directional , ESD Protection Diode.

/ FeaturesStand-off voltage: $\pm 5V$ Max.

Transient protection for each line according to:

IEC61000-4-2(ESD): $\pm 30kV$ (contact).

IEC61000-4-4 (EFT): 40A (5/50ns).

IEC61000-4-5(surge): 8A (8/20 μs).Ultra-low capacitance: $C_J = 10pF$ typ.

Low leakage current.

Low clamping voltage: $V_{CL} = 10.0V$ typ. @ $I_{PP} = 16A$ (TLP).

Solid-state silicon technology.

HF Product.

/ Applications

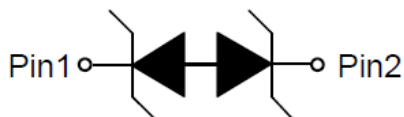
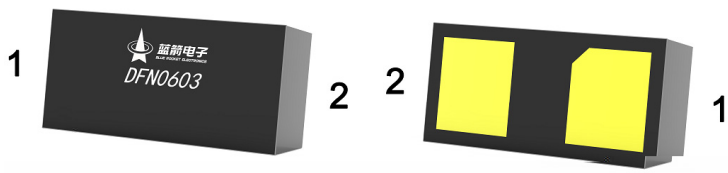
Cellular handsets.

Tablets.

Laptops.

Other portable devices.

Network communication devices.

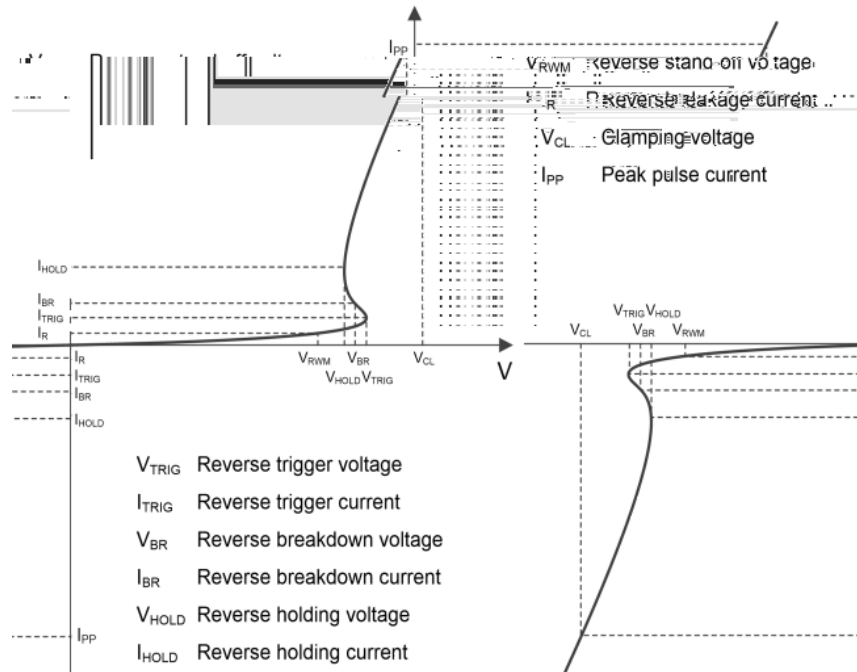
/ Equivalent Circuit**/ Pinning****/ Marking**

See Marking Instructions.

/ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Peak Pulse Power($t_p = 8/20\mu s$)	P_{PK}	35	W
Peak Pulse Current($t_p = 8/20\mu s$)	I_{PP}	8	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	
Junction temperature	T_J	125	
Operating temperature	T_{OP}	-40~85	
Lead temperature	T_L	260	
Storage Temperature	T_{STG}	-55~+150	

/ Electrical Characteristics(Ta=25)



Definitions of electrical characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse maximum working voltage	V_{RWM}				± 5.0	V
Reverse leakage current	I_R	$V_{RWM} = 5.0V$			100	nA
Reverse breakdown voltage	V_{BR}	$I_{BR}=1mA$	5.3	6		V
Reverse holding voltage	V_{HOLD}	$I_{HOLD}=50mA$	5.3	6		V
Clamping voltage ¹⁾	V_{CL}	$I_{PP}=16A$ $t_p=100ns$		10.0		V
Dynamic resistance ¹⁾	R_{DYN}			0.2		Ω
Clamping voltage ²⁾	V_{CL}	$VESD= 8kV$		10.0		V
Clamping voltage ³⁾	V_{CL}	$I_{PP} = 1A$ $t_p = 8/20\mu s$			8	V
		$I_{PP} = 8A$ $t_p = 8/20\mu s$			12	V
Junction Capacitance	C_J	$V_R = 0V$ $f = 1MHz$		10	13	pF
	C_J	$V_R = 2.5V$ $f = 1MHz$		8	11	pF

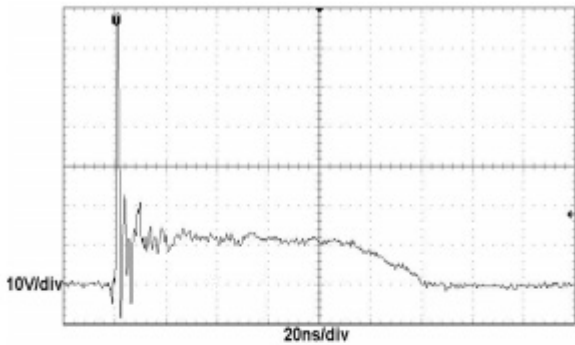
Notes:

1) TLP parameter: $Z_0 = 50\Omega$, $t_p = 100ns$, $t_r = 2ns$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

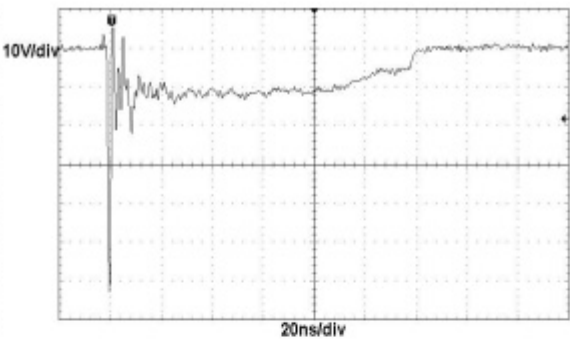
2) Contact discharge mode, according to IEC61000-4-2.

3) Non-repetitive current pulse, according to IEC61000-4-5.

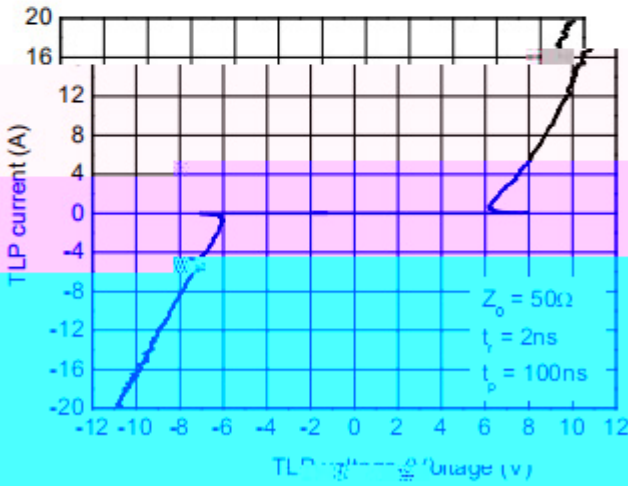
/ Electrical Characteristic Curve(Ta=25)



ESD clamping
(+8kV contact discharge per IEC61000-4-2)



ESD clamping
(-8kV contact discharge per IEC61000-4-2)

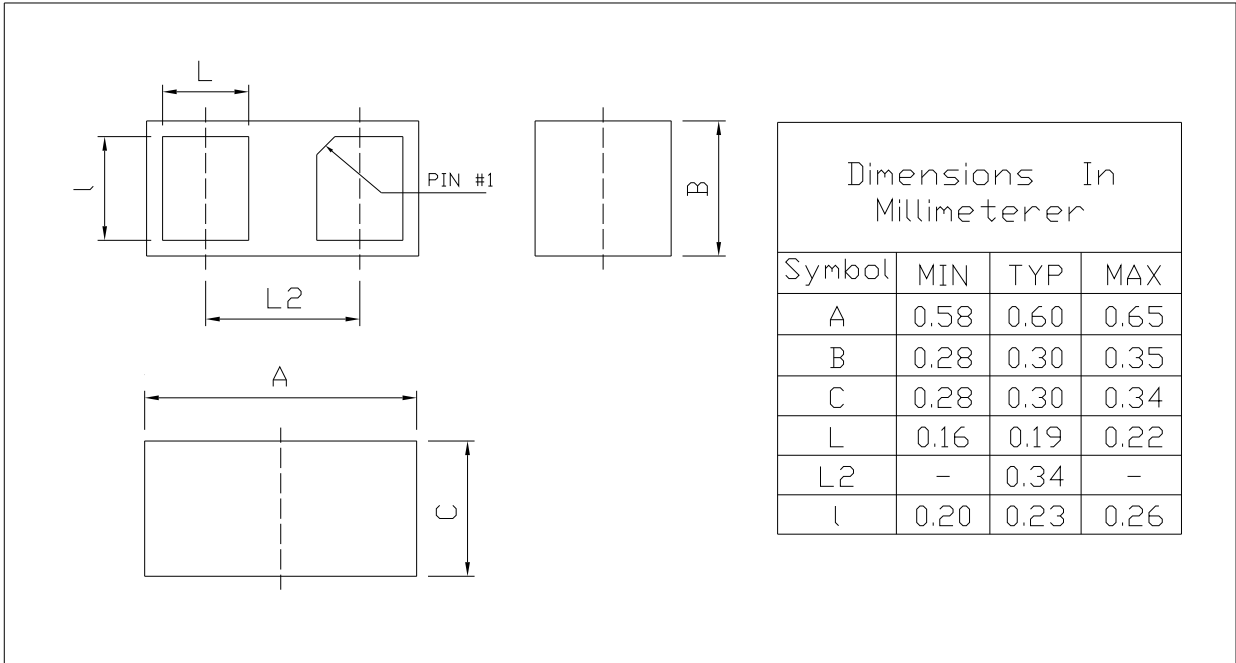


TLP Measurement

/ Package Dimensions

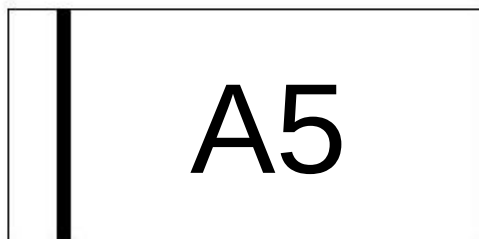
DFN0603

Unit:mm



Rev.02 202102

/ Marking Instructions



A5

Note

A5

Product Type Code

() / Temperature Profile for IR Reflow Soldering(Pb-Free)

- Note:
- 1

150 180 60 90sec;

1.Preheating:150~180 , Time:60~90sec.
- 2

245±5 5±0.5sec;

2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

p.B5w4D